



TS922H

RAIL TO RAIL HIGH OUTPUT CURRENT DUAL OPERATIONAL AMPLIFIER

- RAIL TO RAIL INPUT AND OUTPUT
- LOW NOISE : **9nV/√(Hz)**
- LOW DISTORTION
- HIGH OUTPUT CURRENT : **80mA**
(able to drive 32Ω loads)
- HIGH SPEED : **4MHz, 1.3V/μs**
- OPERATING FROM **2.7V to 12V**
- LOW INPUT OFFSET VOLTAGE : **3.0mVmax**
- ESD INTERNAL PROTECTION : **2KV**
- LATCH-UP IMMUNITY

DESCRIPTION

The TS922 is a RAIL TO RAIL dual BiCMOS operational amplifier optimized and fully specified for 3V and 5V operation.

High output current allows low load impedances to be driven.

The TS922 exhibits a very low noise, low distortion, low offset and high output current capability making this device an excellent choice for high quality, low voltage or battery operated audio systems.

The device is stable for capacitive loads up to 500pF.

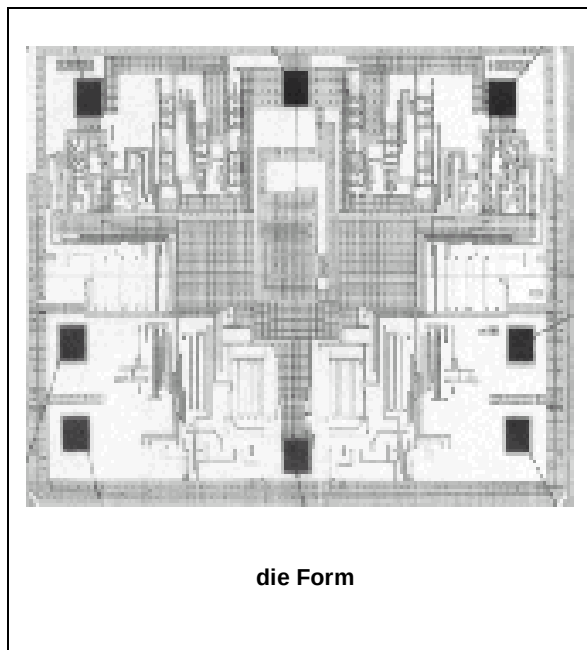
APPLICATIONS

- headphone amplifier
- piezoelectric speaker driver
- sound cards
- MPEG boards, multimedia systems, ...
- line driver, buffer
- cordless telephones and portable communication equipment
- instrumentation with low noise as key factor

ORDER CODE

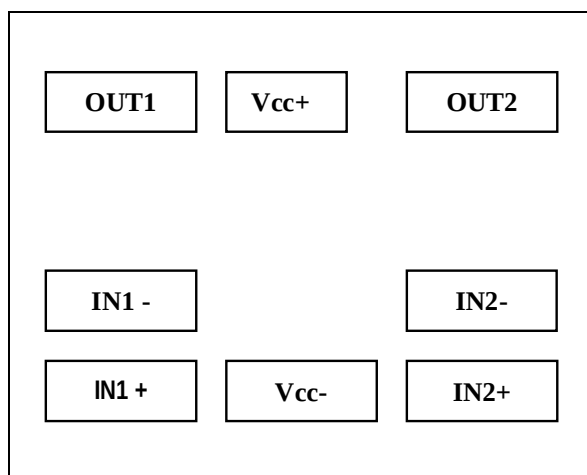
Part Number	Temperature Range	Package		
			Die	
JTS922H-DZD1	-40°C, +150°C		•	

Die = Wafer Form (not sawed)



die Form

PAD CONNECTION



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage ¹⁾	14	V
V_{id}	Differential Input Voltage ²⁾	± 1	V
V_i	Input Voltage ³⁾	-0.3 to 14	V
T_j	Maximum Junction Temperature	155	°C
	Output Short Circuit Duration	see note ⁴⁾	S

1. All voltages values, except differential voltage are with respect to network ground terminal.
2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
3. The magnitude of input and output voltages must never exceed $V_{CC}^+ + 0.3V$.
4. Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous short-circuit on all amplifiers

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	2.7 to 12	V
T_{oper}	Operating Free Air Temperature Range	-40 to +150	°C
V_{icm}	Common Mode Input Voltage Range	$V_{CC}^- - 0.2$ to $V_{CC}^+ + 0.2$	V

ELECTRICAL CHARACTERISTICS
 $V_{CC}^+ = 3V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage $T_{min.} \leq T_{amb} \leq T_{max.}$			3	mV
DV_{io}	Input Offset Voltage Drift		2		$\mu V/^{\circ}C$
I_{io}	Input Offset Current $V_{OUT} = 1.5V$		1	30	nA
V_{oh}	High Level Output Voltage $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$	2.9 2.87	2.63		V
V_{oL}	Low Level Output Voltage $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$		180	50 100	mV
I_{ib}	Input Bias Current $V_{OUT} = 1.5V$		15	100	nA
AVD	Large Signal Voltage Gain ($V_{out} = 2vpk-pk$) $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$		200 35 16		V/mV
I_{cc}	Total Supply Current no load, $V_{out} = V_{cc}/2$		2	3	mA
GBP	Gain Bandwidth Product $R_L = 600\Omega$		4		MHz
CMR	Common Mode Rejection Ratio	60	80		dB
SVR	Supply Voltage Rejection Ratio $V_{cc} = 2.7$ to $3.3V$	60	85		dB
I_o	Output Short Circuit Current	50	80		mA
SR	Slew Rate	0.7	1.3		V/ μs
ϕ_m	Phase Margin at Unit Gain $R_L = 600\Omega$, $C_L = 100pF$		68		Degrees
G_m	Gain Margin $R_L = 600\Omega$, $C_L = 100pF$		12		dB
e_n	Equivalent Input Noise Voltage $f = 1kHz$		9		$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion $V_{out} = 2Vpk-pk$, $F = 1kHz$, $A_v = 1$, $R_L = 600\Omega$		0.005		%
C_s	Channel Separation		120		dB

ELECTRICAL CHARACTERISTICSV_{CC}⁺ = 5V, T_{amb} = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V _{io}	Input Offset Voltage T _{min.} ≤ T _{amb} ≤ T _{max.}			3	mV
DV _{io}	Input Offset Voltage Drift		2		μV/°C
I _{io}	Input Offset Current V _{OUT} = 1.5V		1	30	nA
I _{ib}	Input Bias Current V _{OUT} = 1.5V		15	100	nA
I _{cc}	Total Supply Current no load, V _{out} = V _{cc} /2		2	3	mA
V _{oh}	High Level Output Voltage R _L = 10kΩ R _L = 600Ω R _L = 32Ω	4.9 4.85	4.44		V
V _{oL}	Low Level Output Voltage R _L = 10kΩ R _L = 600Ω R _L = 32Ω		300	50 120	mV
AVD	Large Signal Voltage Gain (V _{out} = 2vpk-pk) R _L = 10kΩ R _L = 600Ω R _L = 32Ω		200 35 16		V/mV
GBP	Gain Bandwidth Product R _L = 600Ω		4		MHz
CMR	Common Mode Rejection Ratio	60	80		dB
SVR	Supply Voltage Rejection Ratio V _{cc} = 3V to 5V	60	85		dB
I _o	Output Short Circuit Current	50	80		mA
SR	Slew Rate	0.7	1.3		V/μs
φ _m	Phase Margin at Unit Gain R _L = 600Ω, C _L = 100pF		68		Degrees
G _m	Gain Margin R _L = 600Ω, C _L = 100pF		12		dB
e _n	Equivalent Input Noise Voltage f = 1kHz		9		$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion V _{out} = 2Vpk-pk, F = 1kHz, A _v = 1, R _L = 600Ω		0.005		%
C _s	Channel Separation		120		dB

SPICE MACROMODEL

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** Standard Linear Ics Macromodels, 1996.
** CONNECTIONS :
* 1 INVERTING INPUT
* 2 NON-INVERTING INPUT
* 3 OUTPUT
* 4 POSITIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY

.SUBCKT TS922 1 3 2 4 5 (analog)
*****
.MODEL MDTH D IS=1E-8 KF=2.664234E-16 CJO=10F
* INPUT STAGE
CIP 2 5 1.000000E-12
CIN 1 5 1.000000E-12
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 8.125000E+00
RIN 15 16 8.125000E+00
RIS 11 15 2.238465E+02
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 153.5u
VOFN 13 14 DC 0
IPOL 13 5 3.200000E-05
CPS 11 15 1e-9
DINN 17 13 MDTH 400E-12
VIN 17 5 -0.100000e+00
DINR 15 18 MDTH 400E-12
VIP 4 18 0.400000E+00
FCP 4 5 VOFP 1.865000E+02
FCN 5 4 VOFN 1.865000E+02
FIBP 2 5 VOFP 6.250000E-03
FIBN 5 1 VOFN 6.250000E-03
* GM1 STAGE *****
FGM1P 119 5 VOFP 1.1
FGM1N 119 5 VOFN 1.1
RAP 119 4 2.6E+06
RAN 119 5 2.6E+06
* GM2 STAGE *****
G2P 19 5 119 5 1.92E-02

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G2N 19 5 119 4 1.92E-02
R2P 19 4 1E+07
R2N 19 5 1E+07
*****
VINT1 500 0 5
GCONVP 500 501 119 4 19.38 !envoi ds VP,
I(VP)=(V119-V4)/2/Ut VP 501 0 0
GCONVN 500 502 119 5 19.38 !envoi ds VN,
I(VN)=(V119-V5)/2/Ut VN 502 0 0
***** orientation isink isource *****
VINT2 503 0 5
FCOPY 503 504 VOUT 1
DCOPYP 504 505 MDTH 400E-9
VCOPYP 505 0 0
DCOPYN 506 504 MDTH 400E-9
VCOPYN 0 506 0
*****
F2PP 19 5 poly(2) VCOPYP VP 0 0 0 0 0.5 !multiplie
I(vout)*I(VP)=Iout*(V119-V4)/2/Ut
F2PN 19 5 poly(2) VCOPYP VN 0 0 0 0 0.5 !multiplie
I(vout)*I(VN)=Iout*(V119-V5)/2/Ut
F2NP 19 5 poly(2) VCOPYN VP 0 0 0 0 1.75 !multiplie
I(vout)*I(VP)=Iout*(V119-V4)/2/Ut
F2NN 19 5 poly(2) VCOPYN VN 0 0 0 0 1.75 !multiplie
I(vout)*I(VN)=Iout*(V119-V5)/2/Ut
* COMPENSATION *****
CC 19 119 25p
* OUTPUT*****
DOPM 19 22 MDTH 400E-12
DONM 21 19 MDTH 400E-12
HOPM 22 28 VOUT 6.250000E+02
VIPM 28 4 5.000000E+01
HONM 21 27 VOUT 6.250000E+02
VINM 5 27 5.000000E+01
VOUT 3 23 0
ROUT 23 19 6
COUT 3 5 1.300000E-10
DOP 19 25 MDTH 400E-12
VOP 4 25 1.052
DON 24 19 MDTH 400E-12
VON 24 5 1.052
.ENDS

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ELECTRICAL CHARACTERISTICS

$V_{CC}^{+} = 3V$, $V_{CC}^{-} = 0V$, R_L , C_L connected to $V_{CC/2}$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Conditions	Value	Unit
V_{io}		0	mV
A_{vd}	$R_L = 10k\Omega$	200	V/mV
I_{CC}	No load, per operator	1.2	mA
V_{icm}		-0.2 to 3.2	V
V_{OH}	$R_L = 10k\Omega$	2.95	V
V_{OL}	$R_L = 10k\Omega$	25	mV
I_{sink}	$V_O = 3V$	80	mA
I_{source}	$V_O = 0V$	80	mA
GBP	$R_L = 600k\Omega$	4	MHz
SR	$R_L = 10k\Omega$, $C_L = 100pF$	1.3	V/ μs
ϕ_m	$R_L = 600k\Omega$	68	Degrees

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